



M T B F

(E I A J R C R - 9 1 0 2)

Model	TUNS100F12
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Re f e r e n c e
1	I C	Monolithic	5	0.2200	
2		Hybrid	0	0.0000	
3	Transistors		33	1.5147	
4	Diodes		35	0.4780	
5	LED•Optocouplers		2	0.1400	
6	Resistors		148	0.4515	
7	Capacitors		72	0.5328	
8	Transformer•Choke Coil		4	0.0920	
9	Connectors		734	0.2443	
10	Others		2	0.1130	
Total Failure Rate [10 ⁻⁶ /H]				3.7863	

M T B F	[H]	265,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—